NSN 5961-01-192-0079

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Inclosure Material:

Metal

Overall Length:

0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.205 inches

End Application:

4920-01-111-2981

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-92

Mounting Method:

Terminal

Terminal Circle Diameter:

0.105 inches

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 collector to base voltage, dc and 40.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, dc

Current Rating Per Characteristic:

200.00 milliamperes source cutoff current

Power Rating Per Characteristic:

625.0 milliwatts small-signal input power, common-collector absolute

Transfer Ratio:

100.0 static forward current transfer ratio, common-emitter and 300.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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